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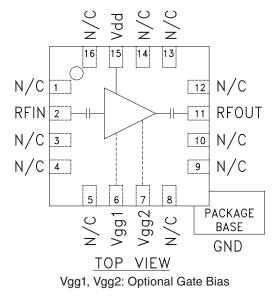


## **Typical Applications**

The HMC441LP3 / HMC441LP3E is a medium PA for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios
- VSAT
- LO Driver for HMC Mixers
- Military EW & ECM

## **Functional Diagram**



# HMC441LP3 / 441LP3E

# GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 6.5 - 13.5 GHz

### Features

Gain: 14 dB Saturated Power: +20 dBm @ 20% PAE Single Supply Voltage: +5V w/ Optional Gate Bias 50 Ohm Matched Input/Output

16 Lead 3x3mm SMT Package: 9mm<sup>2</sup>

## **General Description**

The HMC441LP3 & HMC441LP3E are broadband GaAs PHEMT MMIC Medium Power Amplifiers which operate between 6.5 and 13.5 GHz. The leadless plastic QFN surface mount packaged amplifier provides 14 dB of gain, +20 dBm saturated power at 20% PAE from a +5V supply voltage. An optional gate bias is provided to allow adjustment of gain, RF output power, and DC power dissipation. This 50 Ohm matched amplifier does not require any external components making it an ideal linear gain block or driver for HMC SMT mixers.

# Electrical Specifications, $T_A = +25^{\circ}$ C, Vdd = 5V, Vgg1 = Vgg2 = Open

- 4										
Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range		6.5 - 8.0			8.0 - 11.0	)		11.0 - 13.	5	GHz
Gain	10	13		12	14		10	13		dB
Gain Variation Over Temperature		0.02	0.025		0.02	0.025		0.02	0.025	dB/ °C
Input Return Loss		12			15			14		dB
Output Return Loss		12			15			13		dB
Output Power for 1 dB Compression (P1dB)	13	16		15	18		14	17		dBm
Saturated Output Power (Psat)		18.5			20			19.5		dBm
Output Third Order Intercept (IP3)	23	26		26	29		26	29		dBm
Noise Figure		5.0			4.5			4.75		dB
Supply Current (Idd)		90	115		90	115		90	115	mA

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# HMC441LP3 / 441LP3E

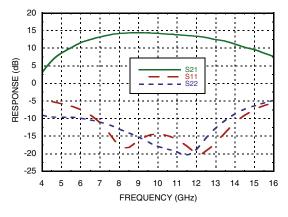
GaAs pHEMT MMIC MEDIUM

POWER AMPLIFIER, 6.5 - 13.5 GHz

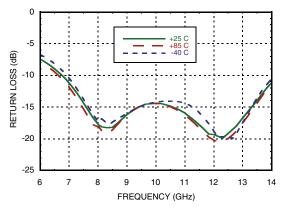
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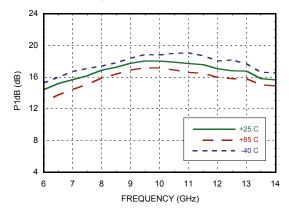
### Broadband Gain & Return Loss



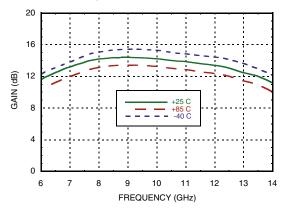
Input Return Loss vs. Temperature



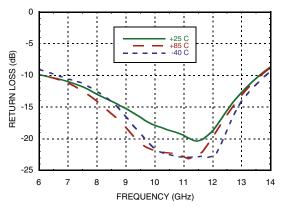
P1dB vs. Temperature



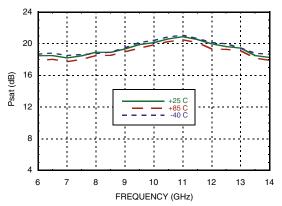
#### Gain vs. Temperature



## Output Return Loss vs. Temperature



### Psat vs. Temperature



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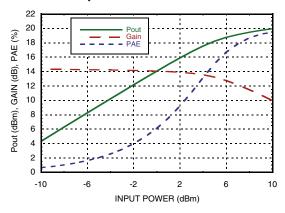
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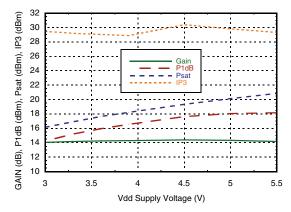
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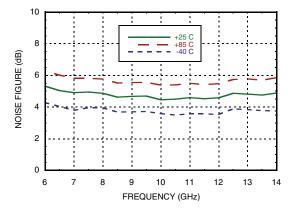
## Power Compression @ 10 GHz



# Gain, Power & Output IP3 vs. Supply Voltage @ 10 GHz



Noise Figure vs. Temperature



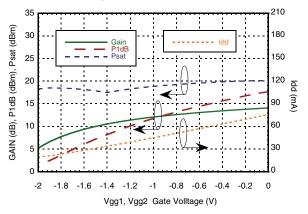
# HMC441LP3 / 441LP3E

# GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 6.5 - 13.5 GHz

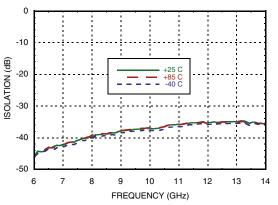
32 28 IP3 (dBm) 24 +25 C +85 C -40 C 20 -16 12 13 6 7 8 10 9 11 14 FREQUENCY (GHz)

Gain, Power & Idd vs. Gate Voltage @ 10 GHz

**Output IP3 vs. Temperature** 



**Reverse Isolation vs. Temperature** 



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## Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+6 Vdc		
	+6 vuc		
Gate Bias Voltage (Vgg1,Vgg2)	-8 to 0 Vdc		
RF Input Power (RFIN)(Vdd = +5 Vdc)	+15 dBm		
Channel Temperature	175 °C		
Continuous Pdiss (T = 85 °C)	0.76 W		
(derate 8.5 mW/°C above 85 °C)			
Thermal Resistance (channel to ground paddle)	118.2 °C/W		
Storage Temperature	-65 to +150 °C		
Operating Temperature	-40 to +85 °C		

# HMC441LP3 / 441LP3E

# GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 6.5 - 13.5 GHz

# Typical Supply Current vs. Vdd

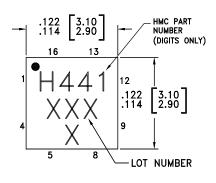
Vdd (V)	ldd (mA)
+5.5	92
+5.0	90
+4.5	88
+3.3	83
+3.0	82

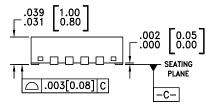
Note: Amplifier will operate over full voltage range shown above

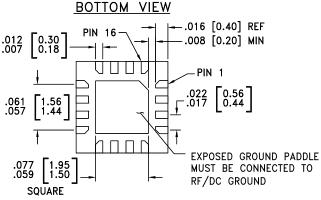


ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

# **Outline Drawing**







#### NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY

- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
- PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
  6. ALL GROUND LEADS AND GROUND PADDLE MUST BE
- SOLDERED TO PCB RF GROUND. 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED
- LAND PATTERN.

### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[3]</sup>	
HMC441LP3 Low Stress Injection Molded Plastic		Sn/Pb Solder	MSL1 <sup>[1]</sup>	441 XXXX	
HMC441LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 <sup>[2]</sup>	441 XXXX	

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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## **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1, 3-5, 8-10, 12-14, 16	N/C	This pin may be connected to RF/DC ground.	
2	RFIN	This pin is AC coupled and matched to 50 Ohms.	
6, 7	Vgg1, Vgg2	Optional gate control for amplifier. If left open, the amplifier will run at standard current. Negative voltage applied will reduce current.	Vgg1 Vgg2
11	RFOUT	This pin is AC coupled and matched to 50 Ohms.	
15	Vdd	Power Supply Voltage for the amplifier. An external bypass capacitor of 100 pF is required.	OVdd ↓ ↓ ↓ ↓ ↓
	GND	Package bottom must be connected to RF/DC ground.	